Am27C020

2 MBit (256K x 8) CMOS EPROM

Advanced Micro Devices

DISTINCTIVE CHARACTERISTICS

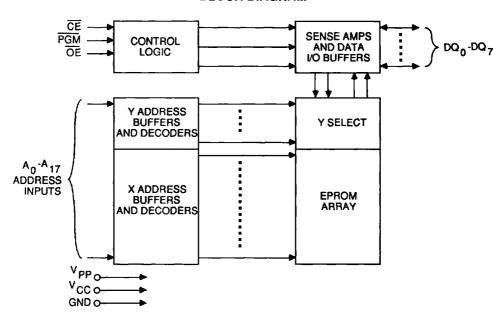
- High-performance CMOS technology
- Fast access time
 - 100 ns
- Low power dissipation
 - 100 µA maximum standby current
- Easy upgrade from 28-pin JEDEC EPROMs
- Compact 32-pin DIP package requires no hardware change for upgrades to 8 Mbit
- Flashrite™ programming
- Ceramic DIP and LCC packages
- Latch-up protected to 100 mA from -1 V to V_{cc} +1 V

GENERAL DESCRIPTION

The Am27C020 is a 2,097,152-bit ultraviolet-light-erasable, programmable read-only memory (UV EPROM) device organized as 256K bytes of 8 bits each. Its pin compatibility with byte-wide JEDEC EPROMs allows easy upgrades from 512K through 8-Mbit densities. AMD's CMOS process technology provides high-speed and low power consumption.

The standard Am27C020 offers access times as fast as 150 ns, allowing operation with high-speed microprocessors without any wait states. The Am27C020 also offers separate Chip Enable (ČE) and Output Enable (ČE) controls, which eliminates bus contention in a mulitple-bus microprocessor system.

BLOCK DIAGRAM

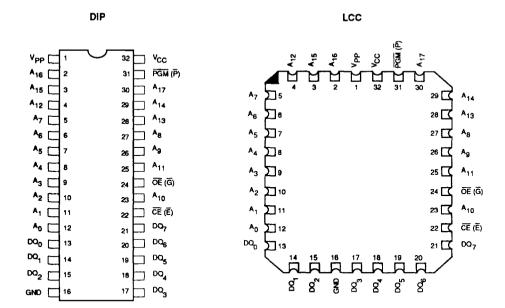


11507-001A

Publication # Rev. Amendment 06140 D /0 Issue Date: February 1989

CONNECTION DIAGRAMS

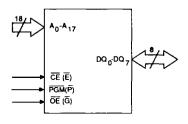
Top View



Note: 1. JEDEC nomenclature is in parentheses.
2. The 32-Pin DIP to 32-Pin LCC configuration varies from the JEDEC 28-Pin DIP to 32-Pin LCC configuration.

11507-002A

LOGIC SYMBOL



11507-003A

Pin Description

Address Inputs

CE (E) Chip Enable Input

DQ,-DQ, Data Input/Outputs

OE (G) = Output Enable Input

PGM (P) = Program Enable Input

= V_{cc} Supply Voltage

= Program Supply Voltage

GND - Ground

3-95